



# PJE8400

## 20V N-Channel Enhancement Mode MOSFET

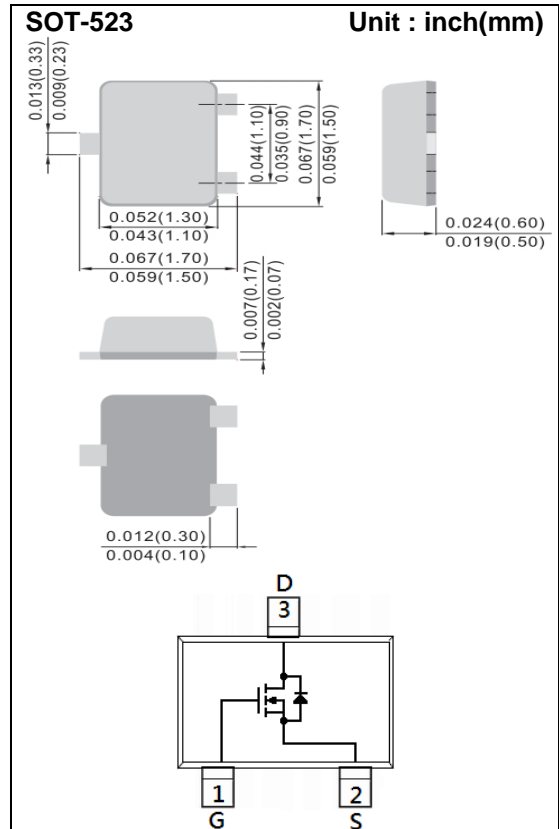
<b>Voltage</b>	<b>20 V</b>	<b>Current</b>	<b>1.1A</b>
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### Features

- $R_{DS(ON)}$  ,  $V_{GS}@4.5V$  ,  $I_D@1.1A < 88m\Omega$
- $R_{DS(ON)}$  ,  $V_{GS}@2.5V$  ,  $I_D@0.7A < 100m\Omega$
- $R_{DS(ON)}$  ,  $V_{GS}@1.8V$  ,  $I_D@0.5A < 130m\Omega$
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

### Mechanical Data

- Case: SOT-523 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.002 grams
- Marking: E00



### Maximum Ratings and Thermal Characteristics ( $T_A=25^\circ C$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		$V_{DS}$	20	V
Gate-Source Voltage		$V_{GS}$	$\pm 12$	V
Continuous Drain Current		$I_D$	1.1	A
Pulsed Drain Current		$I_{DM}$	4.4	A
Power Dissipation	$T_a=25^\circ C$	$P_D$	300	mW
	Derate above $25^\circ C$		2.4	mW/ $^\circ C$
Operating Junction and Storage Temperature Range		$T_J, T_{STG}$	-55~150	$^\circ C$
Typical Thermal resistance		$R_{\theta JA}$	417	$^\circ C/W$
- Junction to Ambient (Note 3)				



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## Electrical Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
<b>Static</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS}=0V, I_D=250\mu A$	20	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	0.4	0.64	1.2	V
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}=4.5V, I_D=1.1A$	-	76	88	m $\Omega$
		$V_{GS}=2.5V, I_D=0.7A$	-	85	100	
		$V_{GS}=1.8V, I_D=0.5A$	-	100	130	
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=20V, V_{GS}=0V$	-	0.01	1	$\mu A$
Gate-Source Leakage Current	$I_{GSS}$	$V_{GS}=\pm 12V, V_{DS}=0V$	-	$\pm 10$	$\pm 100$	nA
<b>Dynamic</b>						
Total Gate Charge	$Q_g$	$V_{DS}=10V, I_D=1.1A,$ $V_{GS}=4.5V$ (Note 1,2)	-	4.6	-	nC
Gate-Source Charge	$Q_{gs}$		-	0.8	-	
Gate-Drain Charge	$Q_{gd}$		-	1	-	
Input Capacitance	$C_{iss}$	$V_{DS}=10V, V_{GS}=0V,$ $f=1.0\text{MHZ}$	-	350	-	pF
Output Capacitance	$C_{oss}$		-	40	-	
Reverse Transfer Capacitance	$C_{rss}$		-	29	-	
<b>Switching</b>						
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=10V, I_D=1.1A,$ $V_{GS}=4.5V,$ $R_G=6\Omega$ (Note 1,2)	-	3.4	-	ns
Turn-On Rise Time	$t_r$		-	47	-	
Turn-Off Delay Time	$t_{d(off)}$		-	18	-	
Turn-Off Fall Time	$t_f$		-	10	-	
<b>Drain-Source Diode</b>						
Maximum Continuous Drain-Source Diode Forward Current	$I_S$	---	-	-	0.4	A
Diode Forward Voltage	$V_{SD}$	$I_S=1A, V_{GS}=0V$		0.74	1.2	V

NOTES :

1. Pulse width  $\leq 300\mu s$ , Duty cycle  $\leq 2\%$
2. Essentially independent of operating temperature typical characteristics.
3.  $R_{\theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
4. The maximum current rating is package limited



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## TYPICAL CHARACTERISTIC CURVES

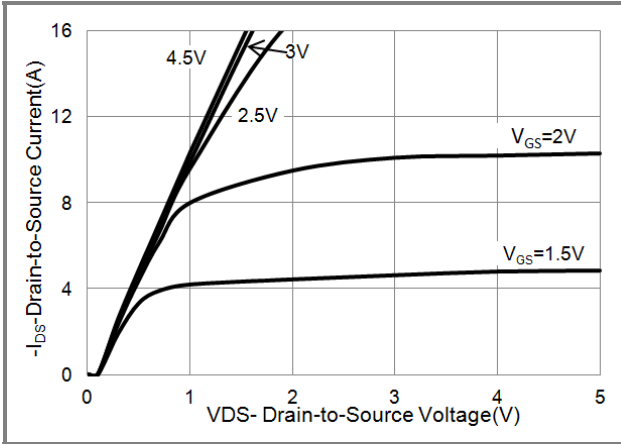


Fig.1 On-Region Characteristics

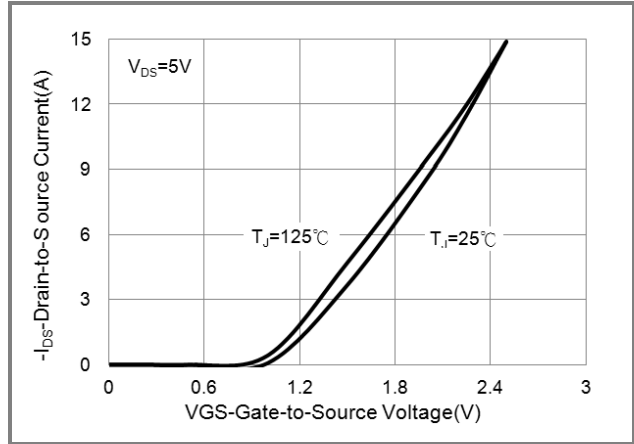


Fig.2 Transfer Characteristics

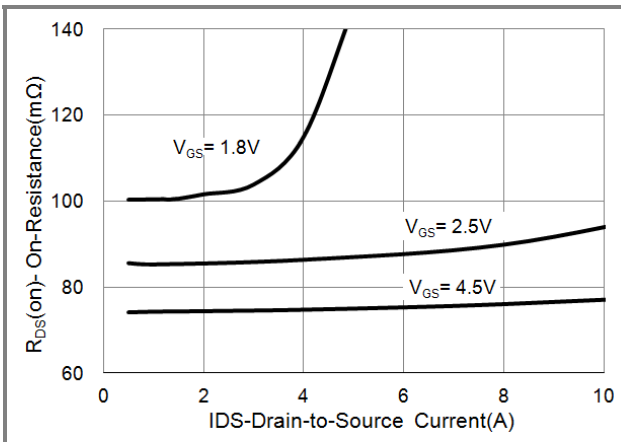


Fig.3 On-Resistance vs. Drain Current

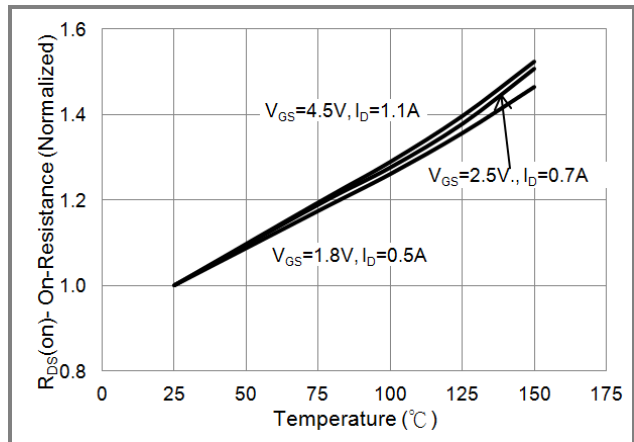


Fig.4 On-Resistance vs. Junction temperature

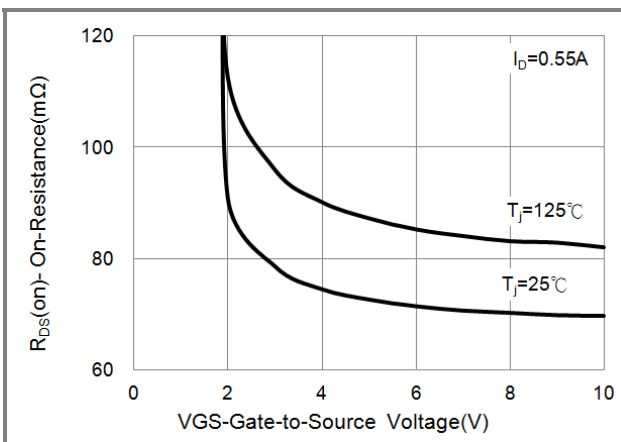


Fig.5 On-Resistance Variation with VGS.

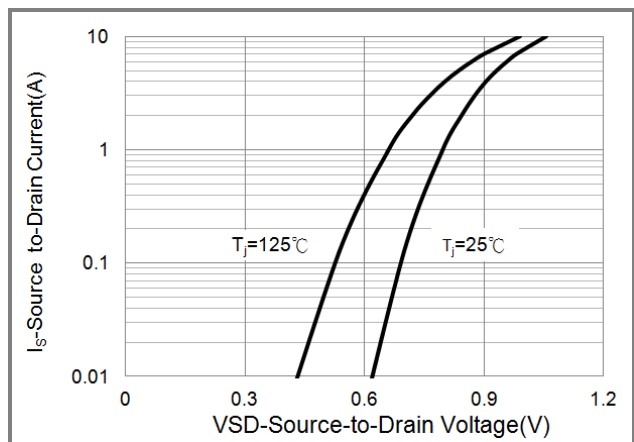


Fig.6 Body Diode Characteristics



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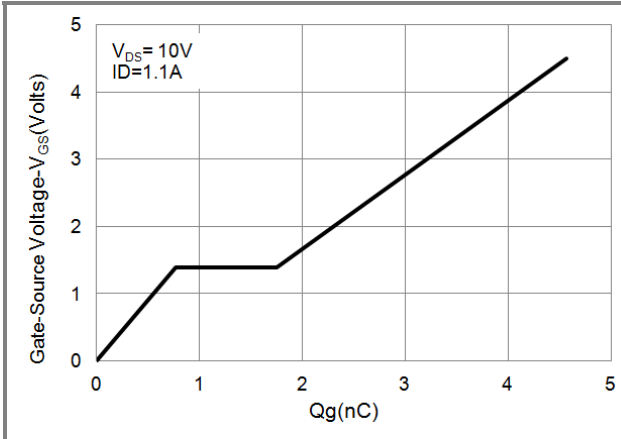


Fig.7 Gate-Charge Characteristics

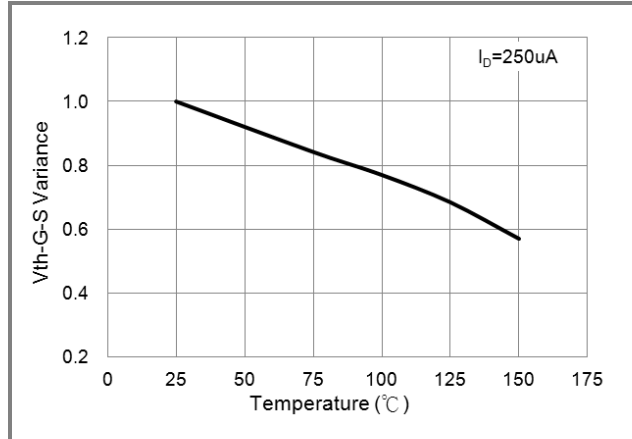


Fig.8 Threshold Voltage Variation with Temperature

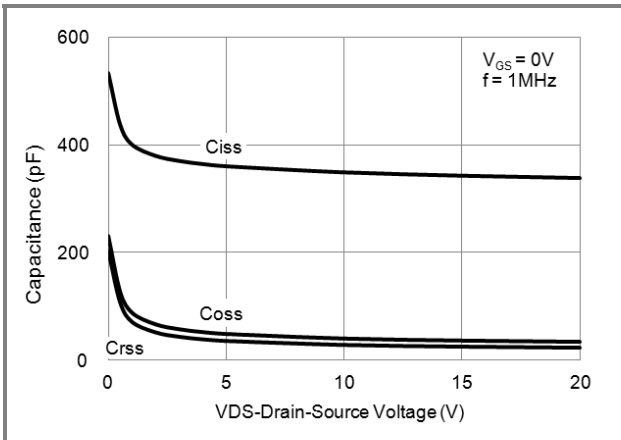


Fig.9 Capacitance vs. Drain-Source Voltage

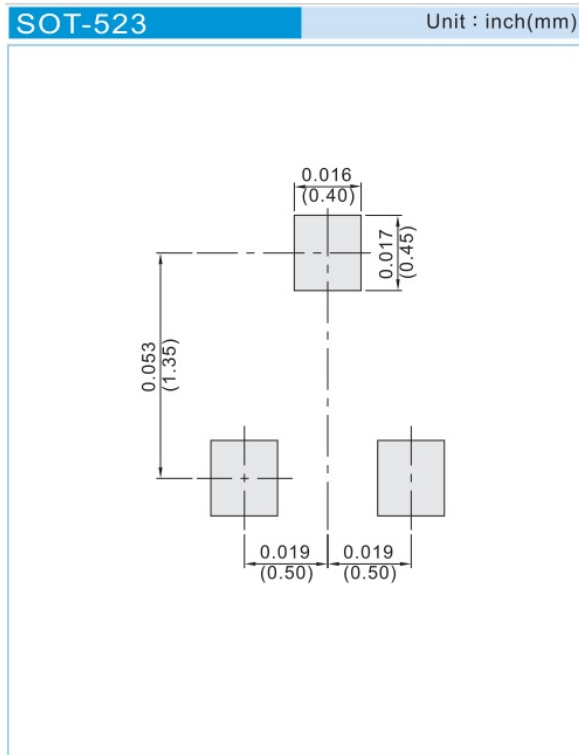


# PJE8400

## PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJE8400_R1_00001	SOT-523	4K pcs / 7" reel	E00	Halogen free

## MOUNTING PAD LAYOUT





## PJE8400

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